



APHB1608LZGKSYKC

1.6 x 0.8 x 0.5 mm Bi-Color Surface Mount LED

DESCRIPTIONS

- The Green source color devices are made with InGaN on Sapphire Light Emitting Diode
- The Super Bright Yellow device is made with AlGaInP (on GaAs substrate) light emitting diode chip
- Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

FEATURES

- 1.6 x 0.8 mm SMD LED, 0.5 mm thickness
- Compatible with reflow soldering
- Available in various color combination
- Package: 2000 pcs / reel
- Moisture sensitivity level: 3
- Tinned pads for improved solderability
- RoHS compliant

APPLICATIONS

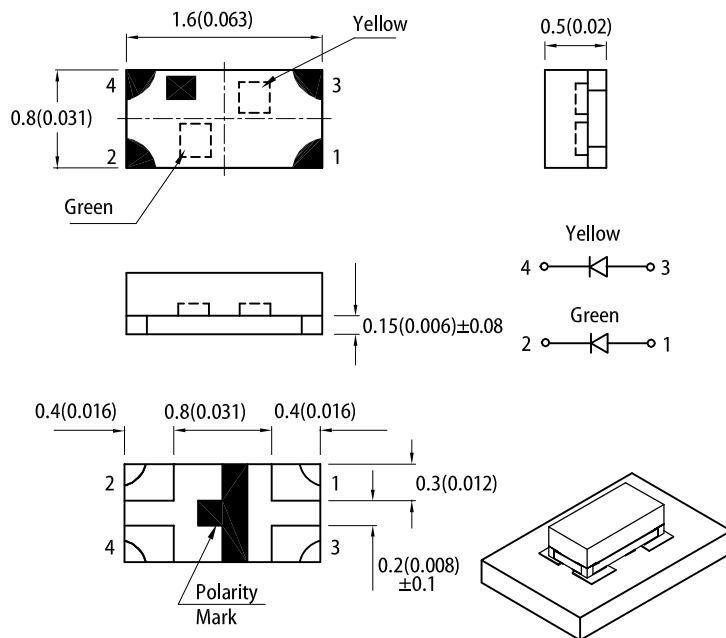
- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices

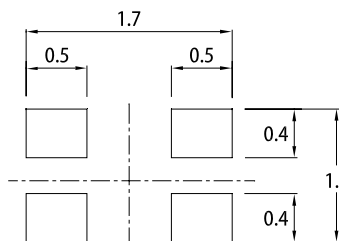


PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.15(0.006") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 2mA ^[2]		Viewing Angle ^[1]
			Min.	Typ.	2θ1/2
APHB1608LZGKSYKC	■ Green (InGaN)	Water Clear	20	40	130°
	■ Super Bright Yellow (AlGaInP)		6	10	

Notes:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity / luminous flux: +/-15%.
3. Luminous intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value			Unit
			Min.	Typ.	Max.	
Wavelength at Peak Emission I _F = 2mA	λ _{peak}	Green Super Bright Yellow	-	515 590	-	nm
Dominant Wavelength I _F = 2mA	λ _{dom} [1]	Green Super Bright Yellow	-	525 590	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 2mA	Δλ	Green Super Bright Yellow	-	35 20	-	nm
Capacitance	C	Green Super Bright Yellow	-	45 20	-	pF
Forward Voltage I _F = 2mA	V _F [2]	Green Super Bright Yellow	2.2 1.5	2.65 1.85	3.1 2.1	V
Reverse Current (V _R = 5V)	I _R	Green Super Bright Yellow	-	-	50 10	uA

Notes:

 1. The dominant wavelength (λ_d) above is the setup value of the sorting machine. (Tolerance λ_d : ±1nm.)

2. Forward voltage: ±0.1V.

3. Wavelength value is traceable to CIE127-2007 standards.

4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value		Unit
		Green	Super Bright Yellow	
Power Dissipation	P _D	102.5	75	mW
Reverse Voltage	V _R	5	5	V
Junction Temperature	T _j	115	115	°C
Operating Temperature	T _{op}	-40 to +85		°C
Storage Temperature	T _{stg}	-40 to +85		°C
DC Forward Current	I _F	25	30	mA
Peak Forward Current	I _{FM} [1]	150	175	mA
Electrostatic Discharge Threshold (HBM)	-	450	3000	V

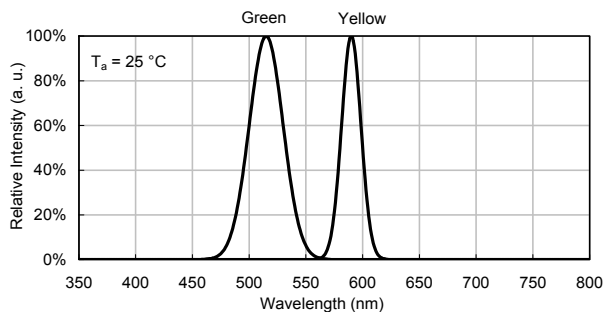
Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

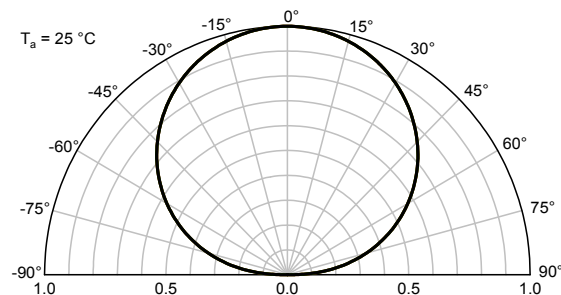
2. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

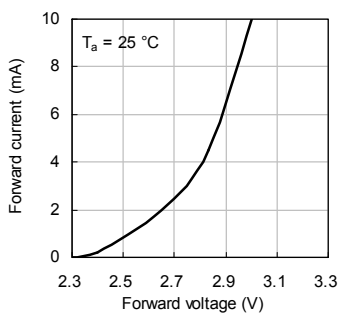


SPATIAL DISTRIBUTION

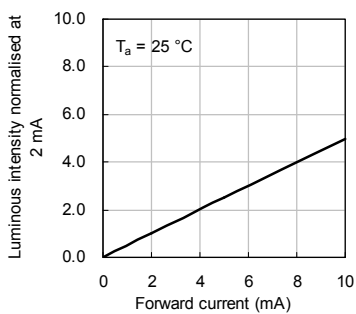


GREEN

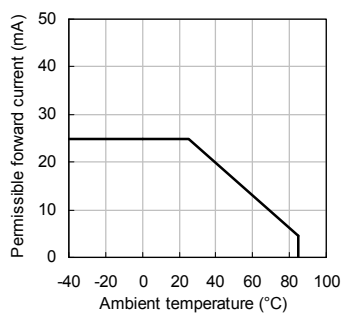
Forward Current vs. Forward Voltage



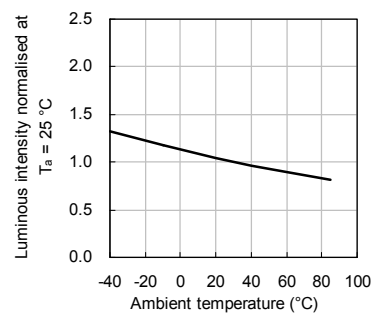
Luminous Intensity vs. Forward Current



Forward Current Derating Curve

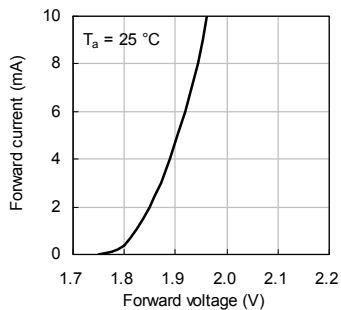


Luminous Intensity vs. Ambient Temperature

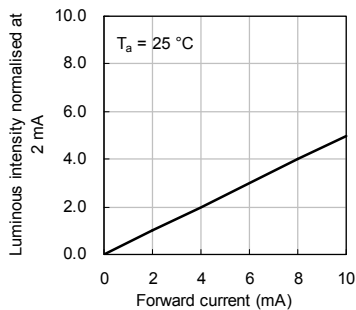


SUPER BRIGHT YELLOW

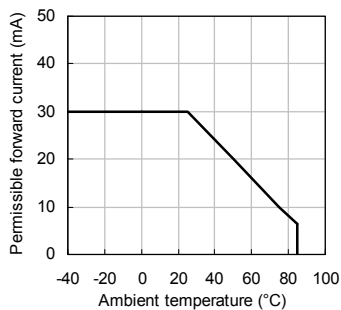
Forward Current vs. Forward Voltage



Luminous Intensity vs. Forward Current



Forward Current Derating Curve



Luminous Intensity vs. Ambient Temperature

